# HOA086X/087X

**Transmissive Sensor** 

#### FEATURES

- Phototransistor output
- Accurate position sensing
- Four mounting configurations
- 0.125 in.(3.18 mm) slot width
- Choice of detector aperture
- Choice of opaque or IR transmissive housings

#### DESCRIPTION

The HOA086X/087X series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black thermoplastic housing. The phototransistor switching takes place whenever an opaque object passes through the slot between emitter and detector. This series allows the user to choose from available options: (1) mounting tab configurations, (2) lead spacing, (3) electro-optical characteristics, (4) detector aperture size, and (5) housing materials.

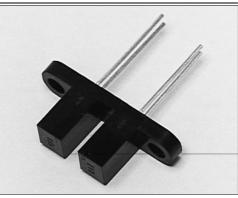
The HOA086X series utilizes an IR transmissive



polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA087X series employs an opaque polysulfone housing with aperture openings for use in applications in which maximum rejection of ambient light is important and in situations where maximum position resolution is desired. The HOA086X/087X series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

To specify the complete product characteristics, see the PART NUMBER GUIDE.



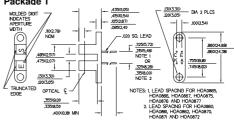
INFRA-33.TIF

OUTLINE DIMENSIONS in inches (mm)

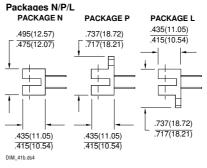
Tolerance

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)

Package T







## Honeywell

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

#### 274

# HOA086X/087X

**Transmissive Sensor** 

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)							
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
IR EMITTER							
Forward Voltage	VF			1.6	V	l <sub>F</sub> =20 mA	
Reverse Leakage Current	R			10	μA	V <sub>R</sub> =3 V	
DETECTOR							
Collector-Emitter Breakdown Voltage	V(BR)CEO	30			V	Ic=100 μΑ	
Emitter-Collector Breakdown Voltage	V(BR)ECO	5.0			V	I <sub>E</sub> =100 μΑ	
Collector Dark Current	ICEO			100	nA	V <sub>CE</sub> =10 V, I <sub>F</sub> =0	
COUPLED CHARACTERISTICS							
On-State Collector Current	C(ON)				mA		
Parameter A		0.5				Vce=10, I <sub>F</sub> =20 mA	
(HOA0860/0865/0870/0875)							
Parameter B		1.0				Vce=5 V, IF=10 mA	
(HOA0861/0866/0871/0876)							
Parameter C		1.8				Vce=0.6, IF=20 mA	
(HOA0862/0867/0872/0877)							
Collector-Emitter Saturation Voltage	VCE(SAT)				V		
Parameter A				0.4		lc=0.4 mA, l⊧=20 mA	
(HOA0860/0865/0870/0875)							
Parameter B				0.4		lc=0.8 mA, l⊧=10 mA	
(HOA0860/0866/0871/0876)							
Parameter C				0.6		lc=1.8 mA, l⊧=20 mA	
(HOA0862/0867/0872/0877)							
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>		15		μs	Vcc=5 V, lc=1 mA RL=1000 Ω	

#### ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted) Operating Temperature Range -40°C to 85°C

Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C
IR EMITTER	
Power Dissipation	100 mW (1)
Reverse Voltage	3 V
Continuous Forward Current	50 mA
DETECTOR	
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	100 mW (1)
Collector DC Current	30 mA

SCHEMATIC Anode Collector

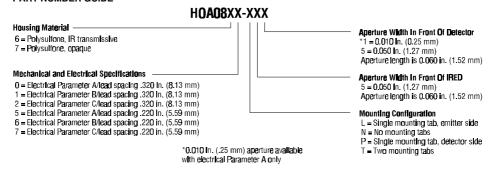
Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

## Honeywell

### HOA086X/087X **Transmissive Sensor**

Fig. 1 **IRED** Forward Bias Characteristics Fig. 2 Non-Saturated Switching Time vs Load Resistance gra\_092.ds4 100 100 Pulsed 90 Forward current - mA condition 80 Ч 70 Response time -= 80 °C +|+||||| - 1 \_1 60  $\perp$ 1 10 50 王王王王 40 Ŧ ΠΠI ŢΙΠΙΠ 30 ΤΙΠΙΠ 20 -40 °C  $\Pi \Pi \Pi \Pi$ 10 -+ -1 0 1000 100 10 1.6 1.8 2.0 0.8 1.0 1.2 1.4 Load resistance - Ohms Forward voltage - V Dark Current vs Fig. 3 Fig. 4 Collector Current vs gra\_301.cdr Temperature Ambient Temperature 1000 1.2 Normalized collector current VCE = 15 V 1.0 100 Dark current - nA H = 00.8 10 0.6 1 0.4 0.2 0.1 0.0 0.01 -25 ò 25 -50 -40 -20 ó 20 40 60 80 100 Free-air temperature - °C Free-air temperature - °C All Performance Curves Show Typical Values

PART NUMBER GUIDE



Honeywell

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

50

75

100

gra\_093.ds4

-| -+ |+||+

=i∓ mm

⊥ШШ

ТПП

10000

gra\_095.ds4

276



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

# Honeywell